

DF40SC3L

30V 40A

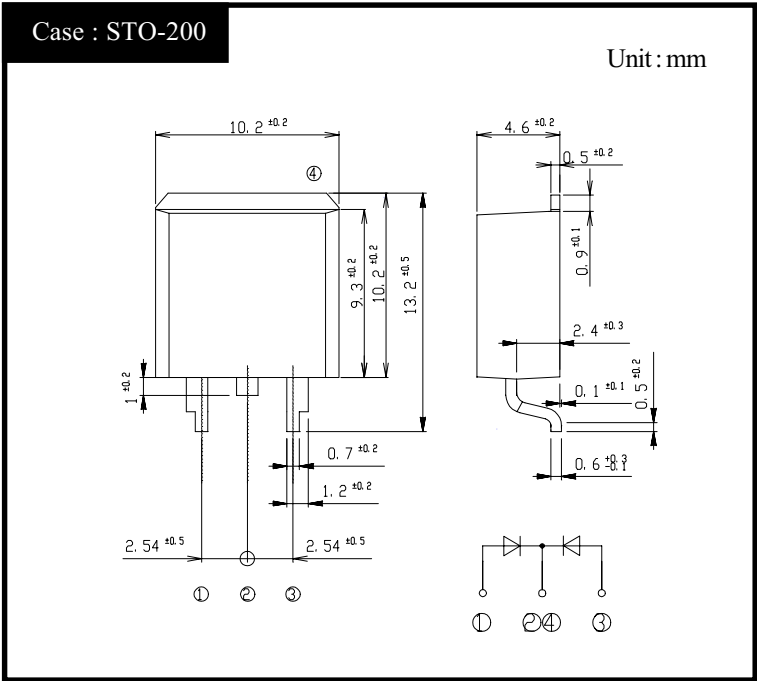
FEATURES

- SMT
- $T_j 150^{\circ}\text{C}$
- Low $V_F=0.45\text{V}$
- P_{RRSM} avalanche guaranteed
- High current capacity with Small Package

APPLICATION

- Switching power supply
- DC/DC converter
- Home Appliances, Office Equipment
- Telecommunication

OUTLINE DIMENSIONS



RATINGS

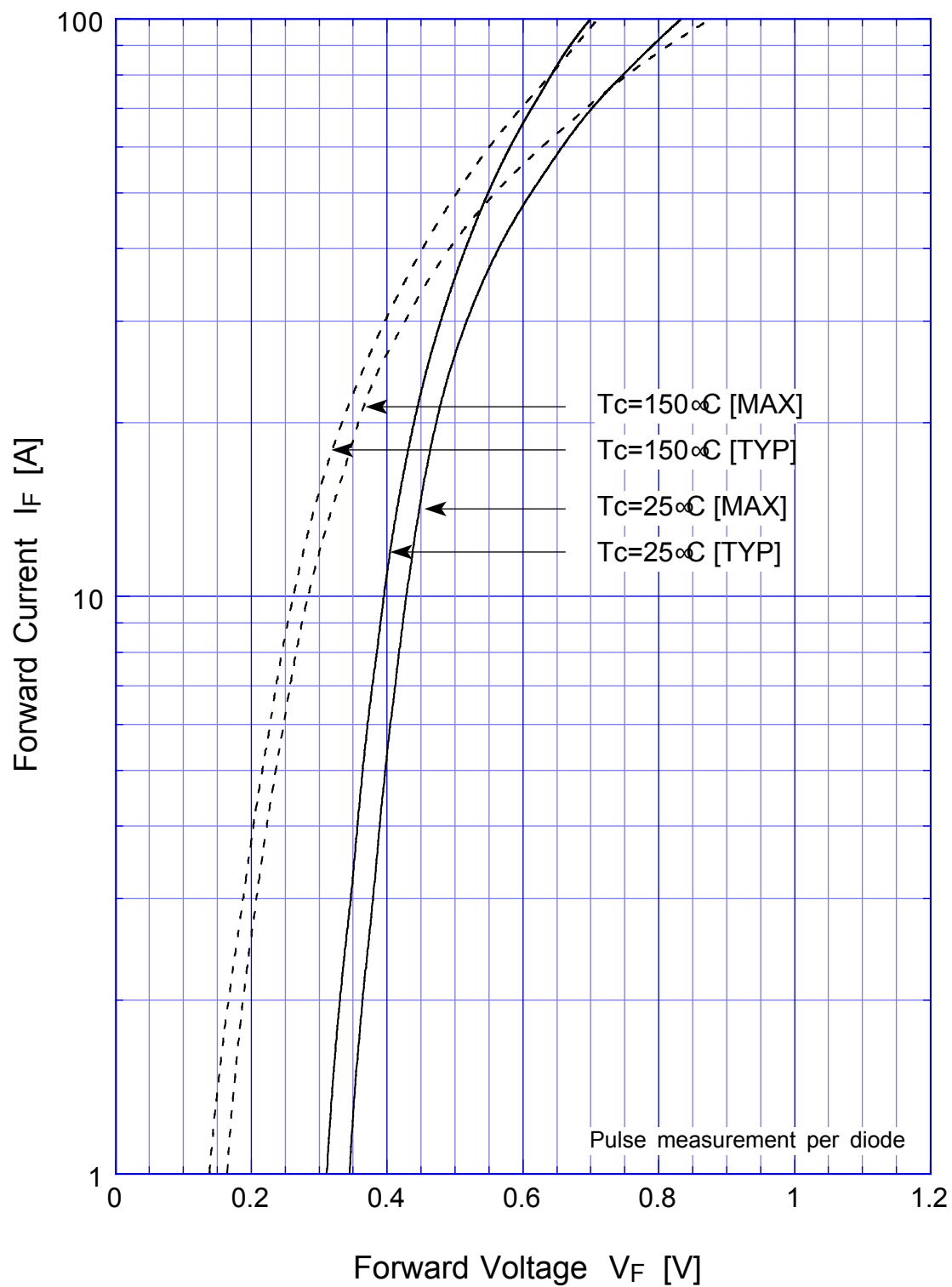
● Absolute Maximum Ratings (If not specified $T_c=25^{\circ}\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		$-55 \sim 150$	$^{\circ}\text{C}$
Operating Junction Temperature	T_j		150	$^{\circ}\text{C}$
Maximum Reverse Voltage	V_{RM}		30	V
Repetitive Peak Surge Reverse Voltage	V_{RRSM}	Pulse width 0.5ms, duty 1/40	35	V
Average Rectified Forward Current	I_O	50Hz sine wave, R-load, Rating for each diode $I_O/2$, $T_c=112^{\circ}\text{C}$	40	A
Peak Surge Forward Current	I_{FSM}	50Hz sine wave, Non-repetitive 1 cycle peak value, Rating of per diode, $T_j=25^{\circ}\text{C}$	400	A
Repetitive Peak Surge Reverse Power	P_{RRSM}	Pulse width $10 \mu\text{s}$, Rating of per diode, $T_j=25^{\circ}\text{C}$	1000	W

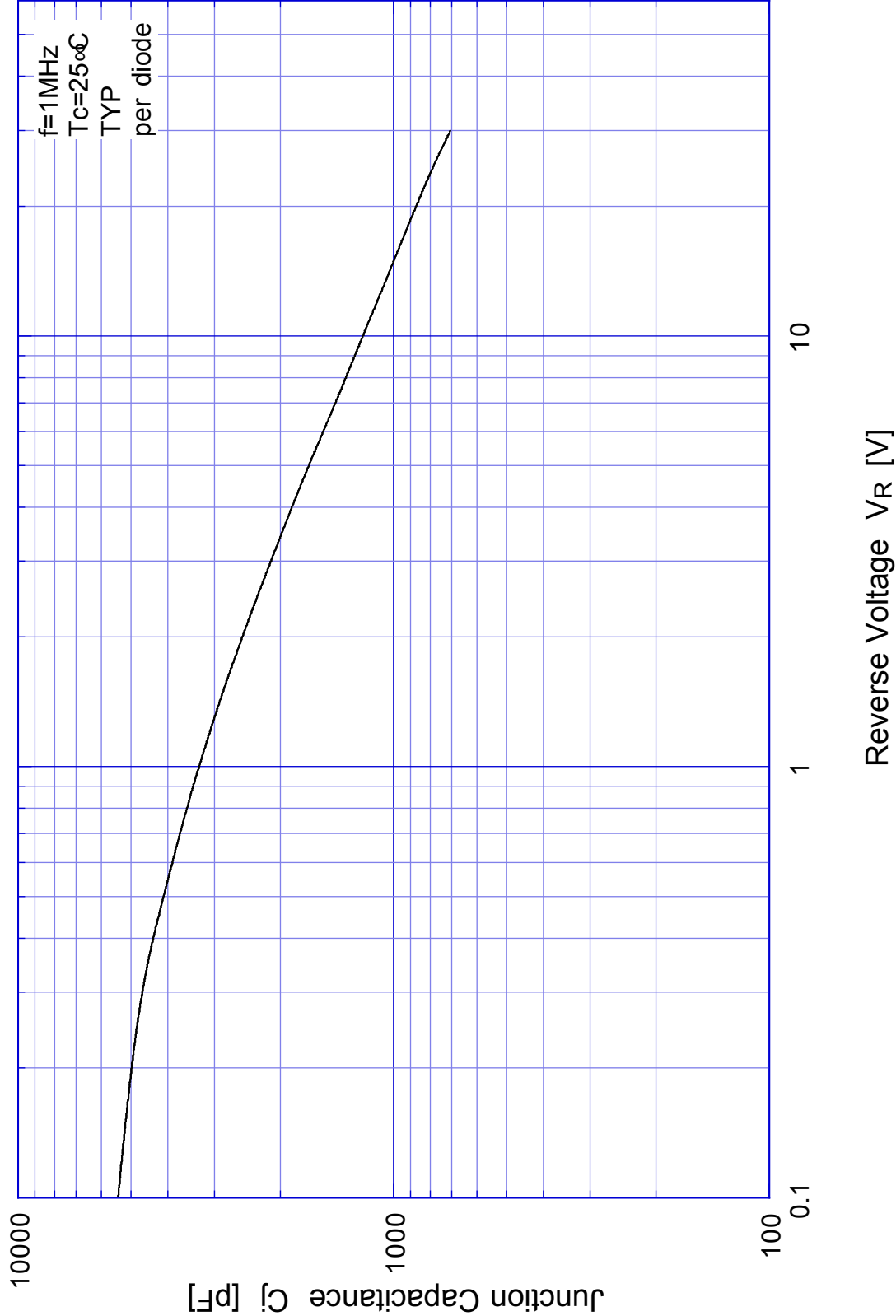
● Electrical Characteristics (If not specified $T_c=25^{\circ}\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V_F	$I_F=15\text{A}$, Pulse measurement, Rating of per diode	Max.0.45	V
Reverse Current	I_R	$V_R=V_{RM}$, Pulse measurement, Rating of per diode	Max.17	mA
Junction Capacitance	C_j	$f=1\text{MHz}$, $V_R=10\text{V}$, Rating of per diode	Typ.1200	pF
Thermal Resistance	θ_{jc}	junction to case	Max.1.5	$^{\circ}\text{C/W}$

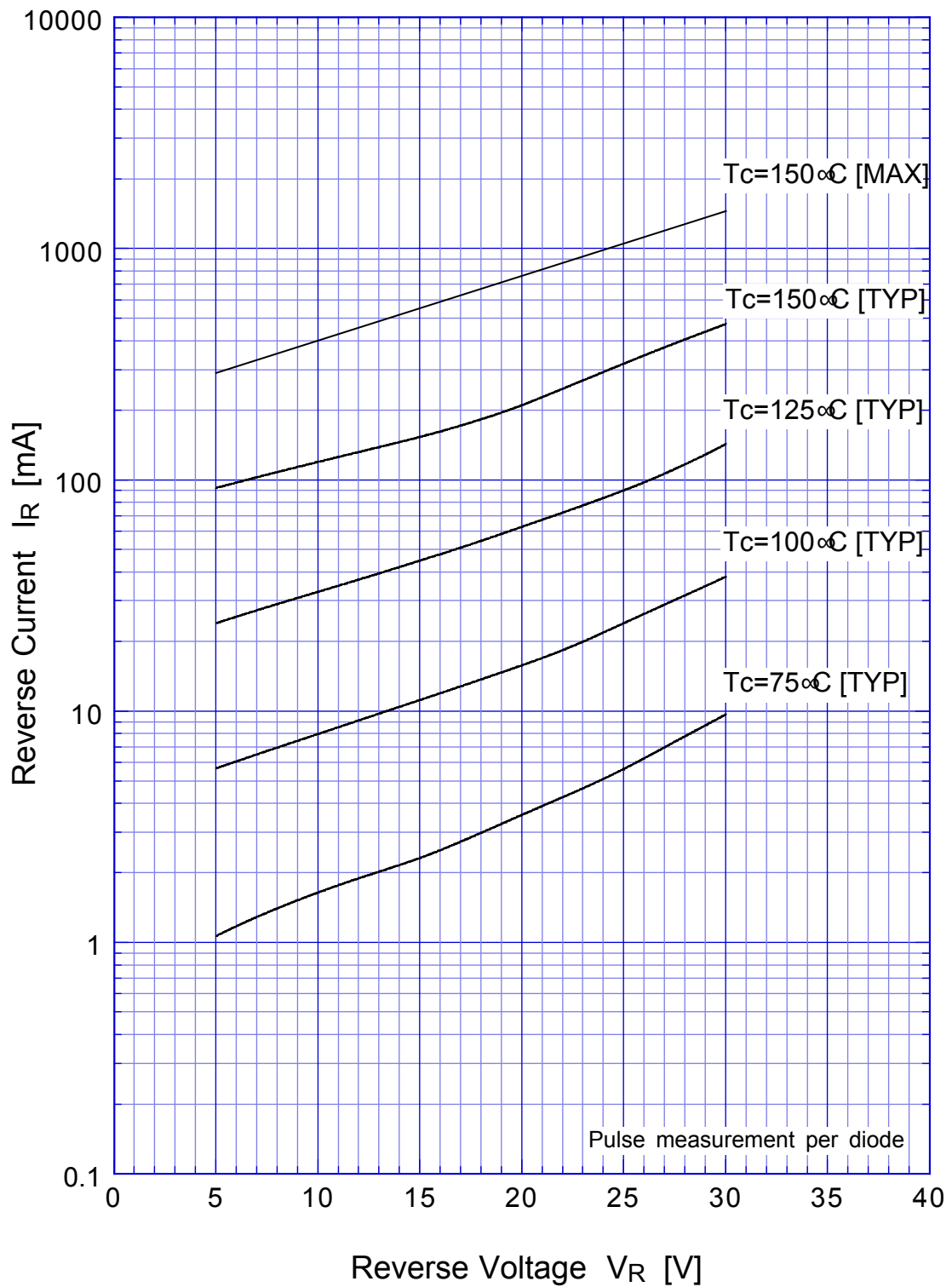
DF40SC3L Forward Voltage



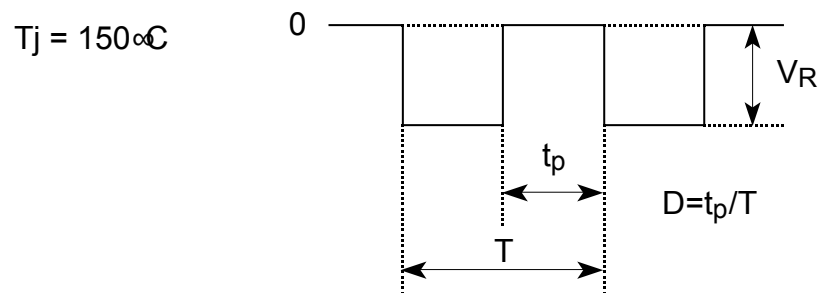
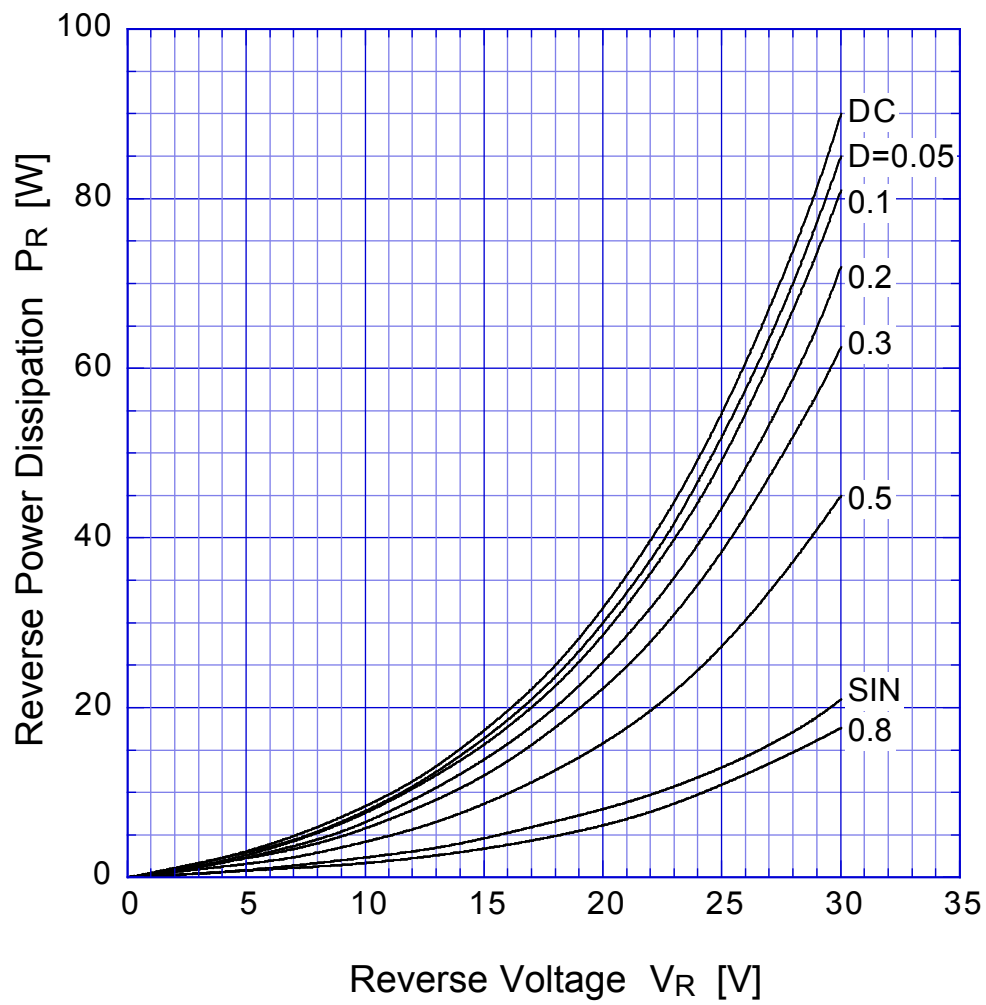
DF40SC3L Junction Capacitance



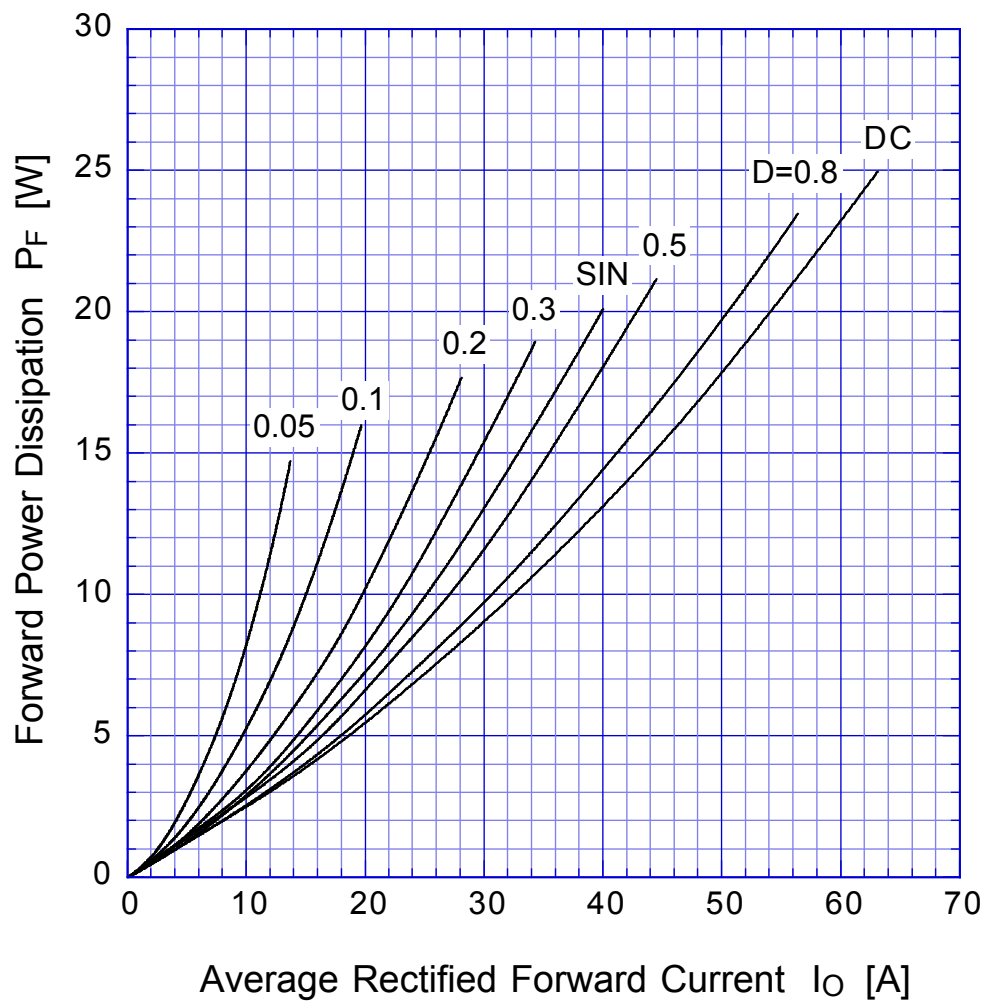
DF40SC3L Reverse Current



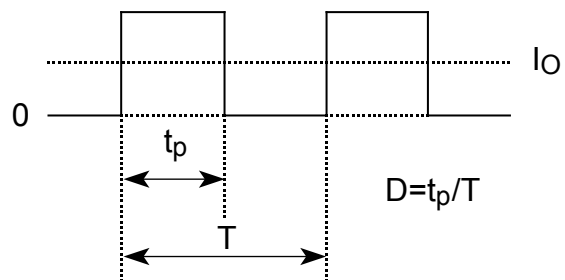
DF40SC3L Reverse Power Dissipation



DF40SC3L Forward Power Dissipation

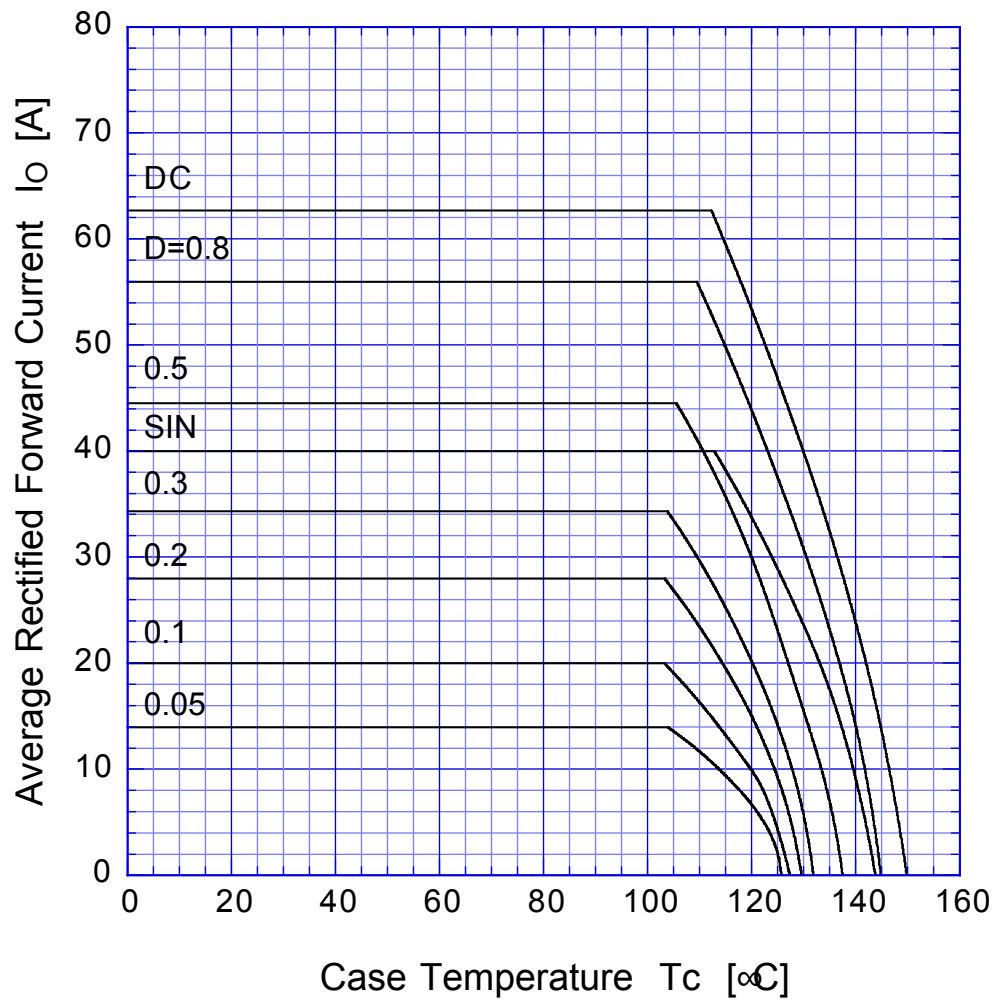


$T_j = 150^\circ\text{C}$

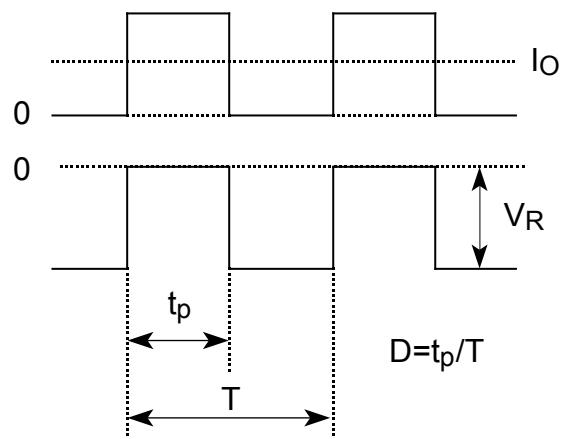


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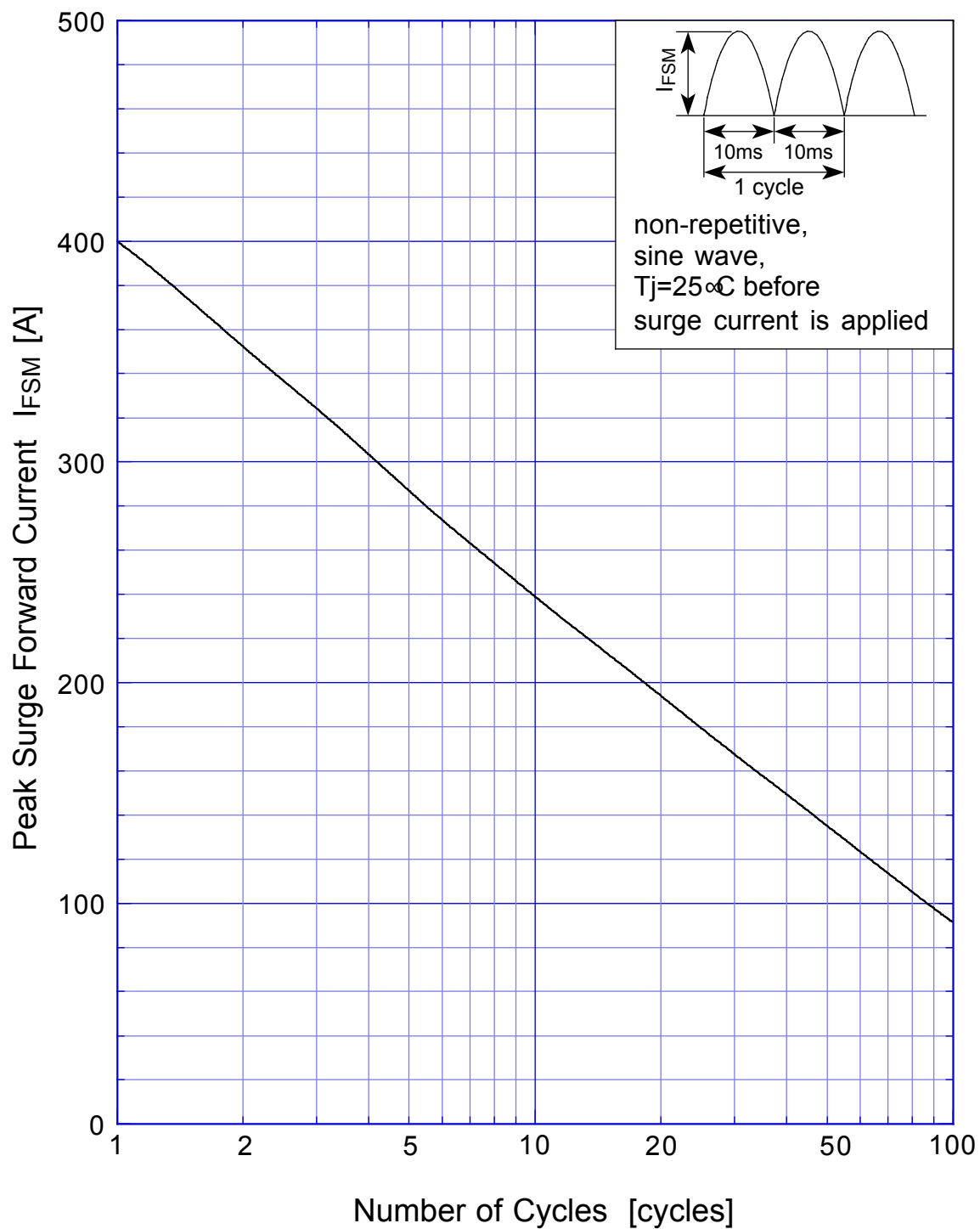
Derating Curve



$V_R = 15\text{V}$



DF40SC3L Peak Surge Forward Capability



SBD Repetitive Surge Reverse Power Derating Curve

